

PN3567

NPN General Purpose Amplifier

- This device is for use as a medium amplifier and switch requiring collector currents up 300mA.
- Sourced from process 19.



1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current - Continuous	600	mA
T _{J,} T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

$\textbf{Electrical Characteristics} \ \, \textbf{T}_{\textbf{A}} = 25 ^{\circ} \textbf{C} \ \, \textbf{unless otherwise noted}$

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characteristics						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	I _C = 30mA, I _B = 0	40			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	80			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = 40V, I _E = 0 V _{CB} = 40V, I _E = 0, T _A = 75°C			50 5	nA μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			25	nA
On Charac	cteristics			•	•	•
h _{FE}	DC Current Gain	V _{CE} = 1V, I _C = 150mA	40		120	
		$V_{CE} = 1V, I_{C} = 30mA$	40			
V _{CE} (sat)	Collector-Emitter Saturation Voltage *	I _C = 150mA, I _B = 15mA			0.25	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 1V, I_{C} = 150mA$			1.1	V
Small Sign	nal Characteristics			•	•	•
C _{obo}	Output Capacitance	$V_{CB} = 10V, I_{E} = 0$			20	pF
C _{ibo}	Input Capacitance	$V_{EB} = 0.5V, I_{C} = 0$			80	

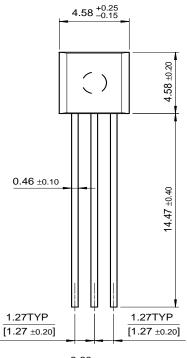
^{*} Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%

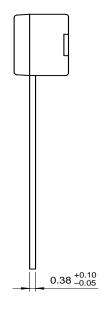
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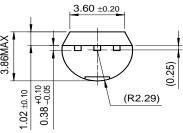
Thermal Characteristics T _A =25°C unless otherwise noted			
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	625 5	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient 83.3		°C/W
$R_{\theta JC}$	Thermal Resistance, Junction to Case	200	°C/W

Package Dimensions

TO-92







Rev. A1, November 2002

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